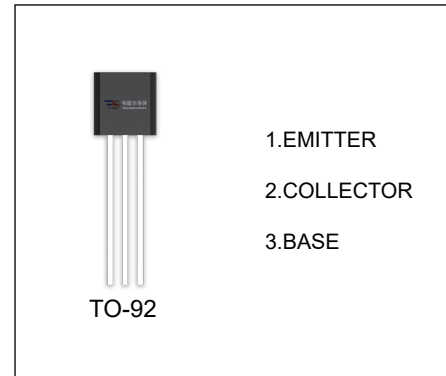


KSD471A TRANSISTOR (NPN)

FEATURES

- Complement To KSB564A
- Low $V_{CE(sat)}$



ORDERING INFORMATION

Part Number	Package	Packing Method	Pack Quantity
KSD471A	TO-92	Bulk	1000pcs/Bag
KSD471A-TA	TO-92	Tape	2000pcs/Box

MAXIMUM RATINGS ($T_a=25^{\circ}\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Base Voltage	40	V
V_{CEO}	Collector-Emitter Voltage	30	V
V_{EBO}	Emitter-Base Voltage	5	V
I_C	Collector Current -Continuous	1	A
P_D	Collector Power Dissipation	800	mW
$R_{\theta JA}$	Thermal Resistance from Junction to Ambient	150	$^{\circ}\text{C} / \text{W}$
T_J, T_{stg}	Operation Junction and Storage Temperature Range	-55~+150	$^{\circ}\text{C}$

$T_a=25\text{ }^\circ\text{C}$ unless otherwise specified

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=0.1\text{mA}, I_E=0$	40			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C=10\text{mA}, I_B=0$	30			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=0.1\text{mA}, I_C=0$	5			V
Collector cut-off current	I_{CBO}	$V_{CB}=30\text{V}, I_E=0$			0.1	μA
DC current gain	h_{FE}	$V_{CE}=1\text{V}, I_C=100\text{mA}$	70		400	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C=1\text{A}, I_B=0.1\text{A}$			0.5	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C=1\text{A}, I_B=0.1\text{A}$			1.2	V
Collector output capacitance	C_{ob}	$V_{CB}=6\text{V}, I_E=0, f=1\text{MHz}$		16		pF
Transition frequency	f_T	$V_{CE}=6\text{V}, I_C=10\text{mA}$		130		MHz

CLASSIFICATION OF h_{FE}

RANK	O	Y	G
RANGE	70-140	120-240	200-400

